

TECHNICAL DATA DATA SHEET 4632, REV.A

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 200 VOLT, 45 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

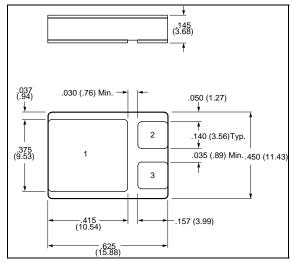
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_c =100 $^{\circ}$ C) (Single)	Io	45	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	200	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	900	pF
MAXIMUM THERMAL RESISTANCE	$R_{ heta JC}$	0.47	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 200	°C

ELECTRICAL CHARACTERISTICS

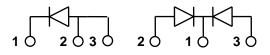
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 45 Amps)			
T _J = 25 °C	V _f	1.07	Volts
T _J = 125°C		0.91	
MAXIMUM REVERSE CURRENT (I _r @ 200 V PIV)			
T _J = 25 °C	l _r	0.3	mA
T _J = 125 °C		3.0	

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MECHANICAL DIMENSIONS: IN Inches / mm



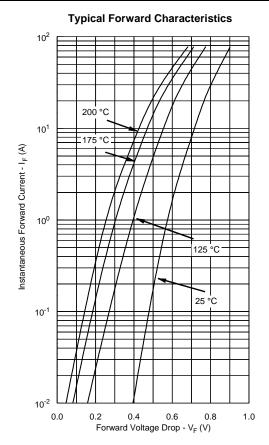
SINGLE COMMON CATHODE

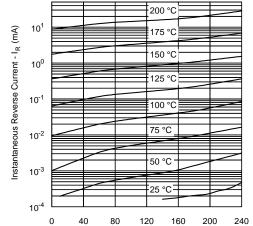


LCC-3P

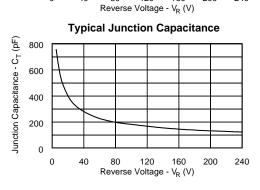
PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE - P	COMMON CATHODE	ANODE 1	ANODE 2





Typical Reverse Characteristics



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